

MAINTENANCE MANUAL

806—825 MHz, 35-WATT POWER AMPLIFIER ASSEMBLY 19D424356GI, G5 806—825 MHz, 25-WATT POWER AMPLIFIER ASSEMBLY 19D424356G3, G6

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DESCRIPTION

The power amplifier assembly uses six RF power transistors to provide a maximum of 35 Watts output power (Mobile) or 25 Watts output power (Station), R24, located on the PA module, is used to adjust the output power to any level from 10 Watts to rated RF power output. The power control circuit consists of R24, Q207, Power Control IC (U1), and a directional coupler.

SUPPLY VOLTAGE AND METERING

Supply voltage is connected through power leads from the system board to feed-through capacitor C219. C219 and C220 prevent RF from getting on the power leads. Diode CR201 will cause the main fuse assembly to blow if the polarity of the power leads is reversed, providing reverse voltage protection for the PA.

Centralized metering jack J205 is provided for use with GE Test Model 4EX3All or Test Kit 4EX8Kl2. The test set meters the AMPL-1 DRIVE (exciter output), the POWER CONTROL voltage, and the DRIVER AND PA CURRENT.

CIRCUIT ANALYSIS

PA ASSEMBLY

The exciter output is coupled through a 50 ohm RF cable to the PA input connector P101. The RF input is coupled through a matching network composed of C2, C3, L1, L2 and L3 to the base of power amplifier Q201.

Part of the RF input is rectified by CR1 and metered at J205-4 through resistor R21. The rectified RF is also applied to the power control IC (U1).

Collector voltage to Q201 is applied from the power controller through collector stabilizing network L5 and R4 and collector feed network L4 and C201.

The output of Q201 is coupled to the base of the second power amplifier Q202 through coupling capacitor C5, and a matching network consisting of C6, C7, L6 and L7.

Collector voltage to Q202 is controlled by power control IC (U1), and Q207 and is applied through a collector stabilizing network L11 and R7 and collector feed network C202 and L10.

The output of Q202 is coupled to the base of power amplifier Q203 through C9 and the matching network of C203, C204, C10, L13, L14 and L15.

The collector voltage to Q203 is coupled directly from the supply voltage through collector stabilizing network L17 and R9 and collector feed network L16 and C11.

The output of Q203 is coupled through an impedance matching network (C206, C13, C207, C208, L18, L19, L20 and L21) and a 50 ohm microstrip W4 that matches the output impedance of Q203 to the input impedance of driver Q204.

The collector voltage of Q204 is coupled through R26 from the supply voltage, through collector stabilizing network L23 and R11, through collector feed network L22 and C15.

Collector current for Q204 is metered across tapped manganin resistor R26. The reading, taken in position "F" on the 10-Volt scale of the Test Set with the High Sensitivity button pressed, should be approximately 2.1 Amperes.



- WARNING -

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Be extremely careful to avoid damaging transistors when working with the PA assembly.

The output of Q204 is coupled through an impedance matching network (C209, C210, C16 and L24) and a 50 ohm microstrip, W5, to a power splitter consisting of microstrip transmission line W6-W9 and R12.

RF output power from Q204 (approximately 12 Watts) is split evenly between two identical class C power amplifiers Q205 and Q206 via their respective identical impedance matching networks. The impedance matching networks consist of C19, C211, C213, L27, L25, and C20, C212, C214, L26 and L27.

Collector voltage for Q205 and Q206 is supplied from the A+ line at J203-1 through identical collector stabilizing networks consisting of R13, L31, and C23, and L32, R14 and C24 respectively.

Collector current for Q205 and Q206 is metered across tapped manganin resistor R27. The reading taken in position G on the 10 Volt scale with the HIGH SENS button on the test set pressed. The meter reading should be 7.9 Amperes.

The output of Q205 and Q206 is coupled through identical impedance matching and RF power combining networks. The RF power combiner consists of microstrip transmission lines W12 and W13 and resistor 15. The combiner adds the outputs of Q205 and Q206 and applies the combined RF output to the low pass filter through 50 ohm microstrip W14.

The RF power output is applied to antenna connector J202 through 50 ohm microstrip W1 in the low pass filter, to the antenna relay in control station and to J202 in mobile PA.

- CAUTION -

The placement of monolithic capacitors on the PA board is very critical; therefore, it is not recommended that the PA board be serviced in the field.

POWER CONTROL CIRCUIT

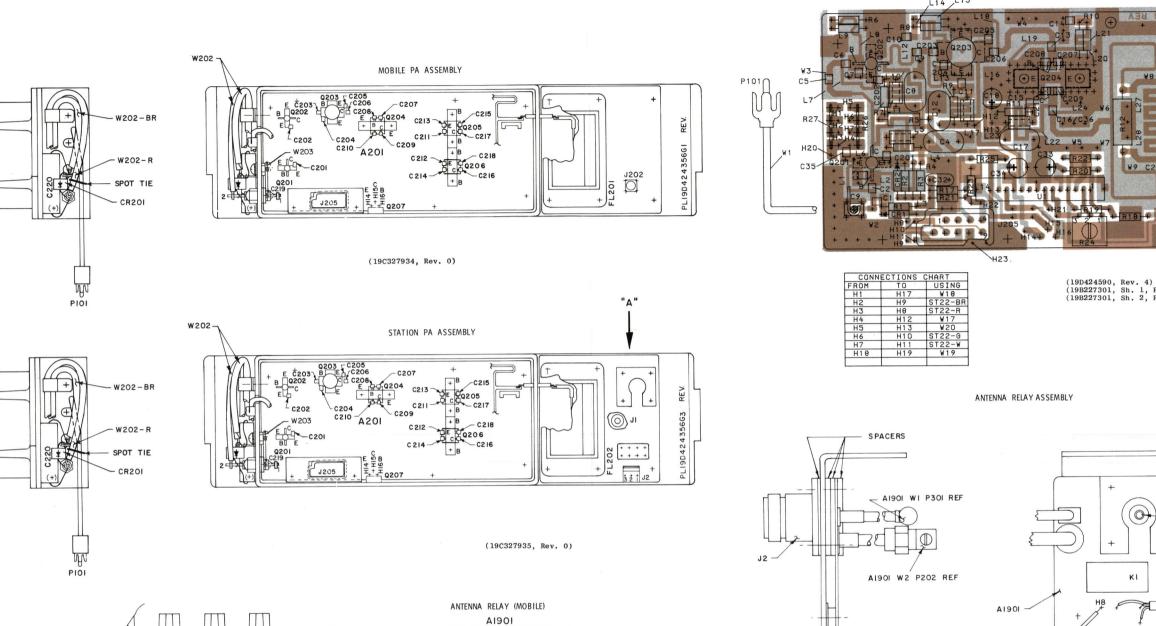
The Power Control Circuit, consists of CR1, U1, Q207 and the directional coupler (C30, C31, CR3, R16 and W15).

When the transmitter is keyed, rectified RF from CRl is applied to a transistorized switch in the Power Control IC (U1), turning on the switch. The switch operates a voltage regulator. The directional coupler senses the forward power at the output of the power amplifier and feeds voltage back to the Power Control IC, resulting in feedback control of the voltage regulator output. A constant voltage is fed via Pin 4 of Ul to Power Adjust potentiometer R24. The setting of R24 determines the voltage fed to the base and collector of Q201 and the collector of Q202. Reducing the supply voltage to these stages reduces the drive to the remaining stages of the power amplifier, thereby reducing the power output of the PA.

Overvoltage sensing of the supply voltage via Pin 11 of U1 shuts down the driver when this comdition occurs, thus protecting the driver and PA stages. The feedback power control performs the function of power leveling of the amplifier output over a range of varying input conditions such as drive level, DC voltage and load variations.

GENERAL ELECTRIC COMPANY • MOBILE COMMUNICATIONS DIVISION
WORLD HEADQUARTERS • LYNCHBURG, VIRGINIA 24502 U.S.A.

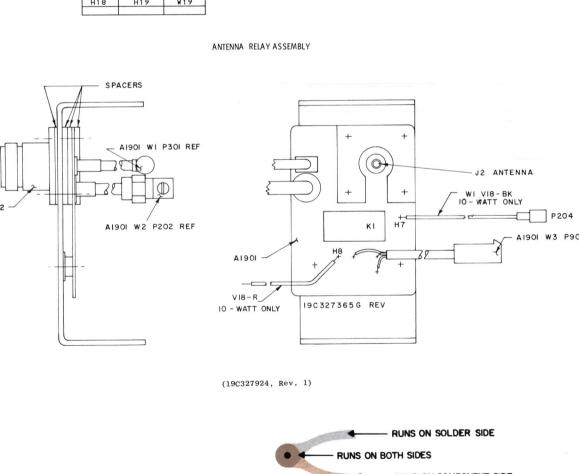


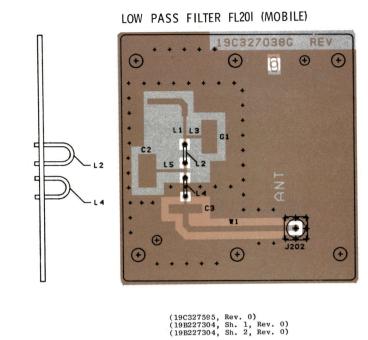


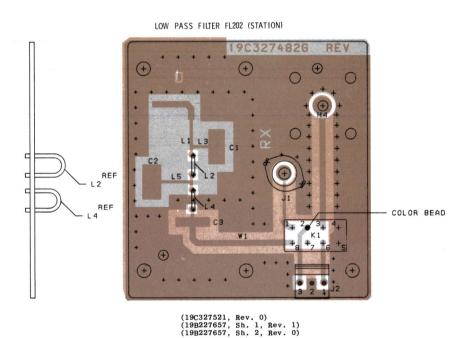
-COLORED BEAD

C3273568 REV

(19C327489, Rev. 1) (19B227558, Sh. 1, Rev. 1) (19B227558, Sh. 2, Rev. 0)







- RUNS ON SOLDER SIDE RUNS ON COMPONENT SIDE

J2 ANTENNA

- A1901 W3 P905 REF

WI VI8-BK

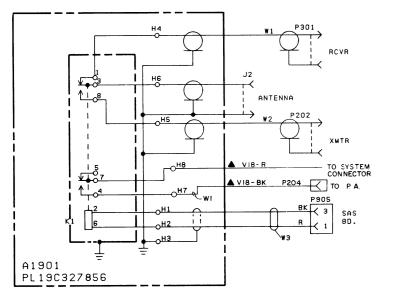
OUTLINE DIAGRAMS

806-825 MHz, PA ASSEMBLY 35-WATT MOBILE TRANSMITTER 25-WATT STATION TRANSMITTER

Issue 4

VIEW "A" (ENLARGED)

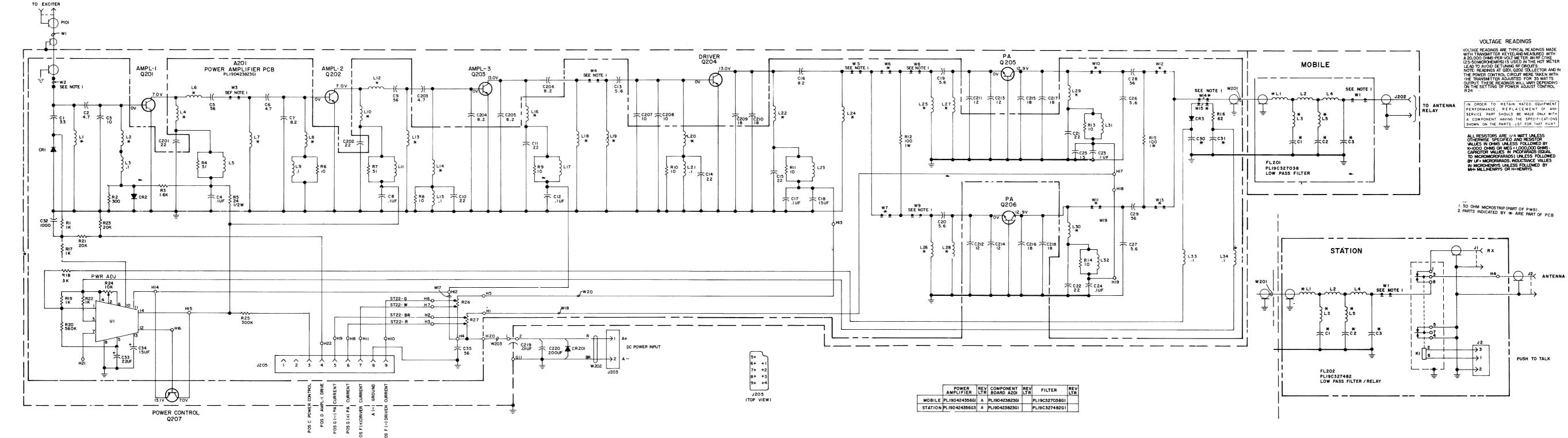
ANTENNA RELAY (MOBILE)



NOTES:
I. A THESE WIRES ARE PART OF 19C327365G2 ONLY

SEE APPLICA	BLE PRODUCTION CHANGE
SHEETS IN I	INSTRUCTION BOOK SECTION
DEALING WIT	TH THIS UNIT, FOR DES-
CRIPTION OF	CHANGES UNDER EACH
REVISION LE	ETTER.
71170 51	LEM DIAG APPLIES TO
1H12 E	LEM UIAG APPLIES TO
MODEL NO	REV LETTER
PL19C327365G1	
PL 19C327365G2	

(19B227557, Rev. 2)



(19R622262, Rev. 6)

SCHEMATIC DIAGRAM

806-825 MHz, PA ASSEMBLY 35-WATT MOBILE TRANSMITTER 25-WATT STATION TRANSMITTER

LBI30469

PARTS LIST
LBI30470E

.806-825 MHz, PA ASSEMBLY
90424356G1 MOBILE
90424356G3 MOBILE
90424356G5 MOBILE SYNTHESIZED

.806-825 MHz, PA ASSEMBLY 19D424356G1 MOBILE 19D424356G3 STATION 19D424356G5 MOBILE SYNTHESIZED 19D424356G6 STATION SYNTHESIZED							
SYMBOL	GE PART NO. DESCRIPTION						
A201		POWER AMPLIFIER BOARD 19D423823G1					
		CAPACITORS					
Cl	19A134419P1	Ceramic: 3.3 pf ±.25 pf, 50 VDCW.					
C2	19A134419P5	Ceramic: 4.7 pf ±.25 pf, 50 VDCW.					
C3	19A134419P13	Ceramic: 10 pf ±5% pf, 50 VDCW.					
C4	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.					
C5	19A134419P31	Ceramic: 56 pf ±5% pf, 50 VDCW.					
C6	19A134419P5	Ceramic: 4.7 pf ±.25 pf, 50 VDCW.					
C7	19A134419P11	Ceramic: 8.2 pf ±5% pf, 50 VDCW.					
C8	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.					
C9	19A134419P31	Ceramic: 56 pf 15% pf, 50 VDCW.					
C10 and	19A134419P21	Ceramic: 22 pf ±5% pf, 50 VDCW.					
C11	1011100000000	Polycotons 0 1 of 10% 50 MDCW					
C12	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.					
C13	19A134419P7	Ceramic: 5.6 pf ±5% pf, 50 VDCW.					
C14 and C15	19A134419P21	Ceramic: 22 pf ±5% pf, 50 VDCW.					
C16	19A134418P11	Ceramic: 8.2 pf ±5% pf, 50 VDCW.					
C17	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.					
C18	19A134202P8	Tantalum: 15 µf ±20%, 20 VDCW.					
C19 and C20	19A134419P7	Ceramic: 5.6 pf ±5% pf, 50 VDCW.					
C21 and C22	19A134418P21	Ceramic: 22 pf ±5% pf, 50 VDCW.					
C23 and C24	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.					
C25	19A134202P8	Tantalum: 15 µf ±20%, 20 VDCW.					
C26 and C27	19A134418P7	Ceramic: 5.6 pf ±5% pf, 50 YDCW.					
C28 and C29	19A134418P31	Ceramic: 56 pf ±5% pf, 50 VDCW.					
C30 and C31		(Part of 19D423824Pl printed board).					
C32	19A116655P19	Ceramic disc: 1000 pf 120%, 1000 VDCW; sim to RMC Type JF Discap.					
C33	19A134202P6	Tantalum: 22 µf ±20%, 15 VDCW.					
C34	19A134202P8	Tantalum: 15 µf ±20%, 20 VDCW.					
C35	19A134419P31	Ceramic: 56 pf ±5% pf, 50 VDCW.					
		DIODES AND RECTIFIERS					
CRl	19A116052Pl	Silicon, hot carrier: Pwd. drop .350 volts max.					
CR2	19A115775P1	Silicon.					
CR3	19A116052P2	Silicon, hot carrier: Fwd. drop .410 volts max.					
J205	19B219374G1	JACKS AND RECEPTACLES Connector: 9 contacts.					

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
			INDUCTORS	R25	3R152P304J	Composition: 300K ohms ±5%, 1/4 w.			JACKS AND RECEPTACLES		19B227679P2	Spacer. (STATION- BOTTOM - Used with antenna
	L1 and		(Part of 19D423824P1 printed board).	R26	19C320212P2	Shunt resistor.	J2	7777145P5	Connector, plug: 1 female contact; sim to Amphenol 82-97 or Military UG-58A/U. (STATION).		19B227679P3	relay jack J2). Spacer. (STATION-CENTER - Used with antenna relay jack J2).
	L2 L3	19B209420P101	Coil, RF: 0.10 µh ±10%, 0.08 ohms DC res max; sim to Jeffers 4416-1K.	R27		INTEGRATED CIRCUITS	J202		(Part ofFL201).		4035306P59	Washer, fiber. (Part of L5,L11,L17,L23,L31,L32). (Not Used).
	LA.		(Part of 19D423824P1 printed board).	U1	19D429709G4	Power Control.	P101				19C321591G5	Heat sink. (Used with Q201-Q203). (MOBILE).
	L5 L6	19A129773G1	Coil. (Part of 19D423824Pl printed board).	Wl	19A136858G1				TRANSISTORS		19C321591G7 7139898P3	Heat sink. (Used with Q201-Q203). (STATION). Hex nut, brass: 1/4-28. (Secures C219).
	thru L8			W2 thru		(Part of 19D424824P1 printed board).	Q201 Q202	19A134430P1 19A134430P2	Silicon, NPN. Silicon, NPN.		19B201074P305	Tap screw, Phillips POZIDRIV [®] : No. 6-32 x 5/16. (Secures A201).
-	L9	19B209420P101	Coll, RF: 0.10 µh ±10%, 0.08 ohms DC res max; sim to Jeffers 4416-1K.	W15 W17	19B227659P4	Jumper.	Q203	19A134431P1	Silicon, NPN.		19A134016P1 19A116023P1	Insulator, bushing. (Used with Q207). Insulator, plate. (Used with Q207).
	L10 L11	19A129773G1	(Part of 19D423824Pl printed board). Coil.	W18	19B227659P2	Jumper.	Q204 Q205	19A134432P1 19A134433P1	Silicon, NPN. Silicon, NPN.		5492178P2	Washer. (Used with Q201-Q203).
	L12 thru		(Part of 19D423824Pl printed board).	W19 W20	19B227659P1 19B227659P3	Jumper. Jumper.	and Q206	15/15/15/1	,		19A121006P14	Washer. (Used with Q201 & Q202). Nut, hex: No 8-32. (Used with Q201-Q203).
	L14 L15	19B209420P101	Coil, RF: 0.10 µh ±10%, 0.08 ohms DC res max;				Q207	19A116942P1	Silicon, PNP.		N207P15C6	Nut, hea. No 8-32. (used with quot quot).
	L16		sim to Jeffers 4416-lK. (Part of 19D423824Pl printed board).	C201 and	19A134419P21	Ceramic: 22 pf ±5% pf, 50 VDCW.	w201	19A136859G1				
	L17	19A129773G1	Coil.	C202 C203	19A134419P5	Ceramic: 4.7 pf ±.25 pf, 50 VDCW.	W202A	19B227058G1	Cable: approx 1 foot long.			
	L18 thru L20		(Part of 19D423824Pl printed board).	C204 thru	19A134419P11	Ceramic: 8.2 pf ±5% pf, 50 VDCW.	₩202B	19B227058G2	Cable: approx 1 foot long.			
	L21	19B209420P101	Coil, RF: 0.10 µh ±10%, 0.08 ohms DC res max; sim to Jeffers 4416-1K.	C206 C207	19A134419P13	Ceramic: 10 pf ±5% pf, 50 VDCW.	W203	19B227659P5	Jumper.			
	L22		(Part of 19D423824Pl printed board).	and C208					ASSOCIATED ASSEMBLIES			
	L23 L24	19A129773G1	Coil. (Part of 19D423824P1 printed board).	C209 and C210	19A134418P19	Ceramic: 18 pf ±5% pf, 50 VDCW.			MOBILE ANTENNA RELAY 19C32736561			
	thru L30		, , , , , , , , , , , , , , , , , , , ,	C211 thru C214	19A134419P15	Ceramic: 12 pf ±5% pf, 50 VDCW.			19032130301			
	L31 and L32	19A129773G1	Coil.	C215 thru C218	19A134418P19	Ceramic: 18 pf ±5% pf, 50 VDCW.	A1901		COMPONENT BOARD 19C327856G1			
	L33 and	19B209420P101	Coil, RF: 0.10 µh ±10%, 0.08 ohms DC res max; sim to Jeffers 4416-1K.	C219	19A116708P1	Ceramic, feed-thru: 0.01 µf +100% -0%, 500 VDCW; sim to Erie 327050X-5W0103P.	K 1	19A700061P1	Hermetic sealed: 180-341 ohms coil res, 8-16.3			
	L34			C220*	19A115680P10	Electrolytic: 200 µf +150% -10%, 18 VDCW; sim to Mallory Type TTX.			VDC; sim to GE 3SAV1760A2, CP Clare HFW-1201558, or Potter-Brumfield HCM6160.			
	P101		(Part of W1).		19A115680P5	Earlier than REV A: Electrolytic: 100 µf +150% -10%, 25 VDCW; sim			PLUGS	İ		
		10.4500100700			ISATISOCOFS	to Mallory Type TTX.	P202 P301		(Part of W2). (Part of W1).			
	R1 R2	19A700106P63 3R152P301J	Composition: 1K ohms ±5%, 1/4 w. Composition: 300 ohms ±5%, 1/4 w.		10411679201	DIODES AND RECTIFIERS Rectifier, silicon: 100 VDC blocking, 6 amps.	P905		(Part of W3).			
	R3	3R152P162J	Composition: 1.6K ohms ±5%, 1/4 w.	CR201	19A116783P1					1		
	R4 R5	19A700106P32 3R77P240J	Composition: 51 ohms ±5%, 1/4 w. Composition: 24 ohms ±5%, 1/2 w.	FL201	19C327038G1	Lowpass Filter. (MOBILE).	W1	19A136861G1	Cable, RF: approx 5-1/2 inches long. Includes (P301) 7104941P21.			1
	R6	19A700106P15	Composition: 10 ohms ±5%, 1/4 w.	FL202		STATION 800 MHz FILTER/RELAY ASSEMBLY	w2	19B227567G1	Cable, RF: approx 14-1/4 inches long. Includes (P202) 19A134413P4.			1
	R7 R8	19A700106P32 19A700106P15	Composition: 51 ohms ±5%, 1/4 w. Composition: 10 ohms ±5%, 1/4 w.			19C327482G1	W3	19A136804G1	Cable: approx 22 inches long. Includes (P905) 19A116659P14.			
	thru R11								JACKS AND RECEPTACLES			
	R12 R13	19A700112P39 19A700106P15	Composition: 100 ohms ±5%, 1 w. Composition: 10 ohms ±5%, 1/4 w.	J1	19A130924G1	Receptacle, coaxial: jack type; sim to Cinch 14H11613.	J2	7777145P5	Connector, plug: 1 female contact; sim to Amphenol 82-97 or Military UG-58A/U. (MOBILE).			
	and R14			J2	19A116659P55	Connector, printed wiring: 3 contacts; sim to Molex 09-65-1031.			MISCELLANEOUS			
	R15 R16	19A700112P39 3R152P620J	Composition: 100 ohms ±5%, 1 w. Composition: 62 ohms ±5%, 1/4 w.			RELAYS		19B226952G3	PA Cover. Support. (J2).			
	R17	19A700106P63	Composition: 1K ohms ±5%, 1/4 w.	K1	19A700061P1	Hermetic sealed: 180-341 ohms coil res, 8-16.3 VDC; sim to GE 3SAV1760A2, CP Clare HFW-1201558, or Potter-Brumfield HCM6160.		19A136798G1 19B227679P1	Spacer. (MOBILE- Quantity 3- Used with Antenna			
max.	R18	3R152P302J 19A700106P63	Composition: 3K ohms ±5%, 1/4 w. Composition: 1K ohms ±5%, 1/4 w.			INDUCTORS		19B227679P2	Relay). Spacer. (MOBILE- Quantity 1- Used with Antenna			
max.	R19 R20	3R152P564J	Composition: 16 Onms 105, 174 w.	L2	19A136863P1	Coil.		19B227679P1	Relay). Spacer. (STATION- TOP - Used with antenna relay			
	R21	3R152P203J	Composition: 20K ohms ±5%, 1/4 w.	L4	19A136863P1	Coil.			jack J2).			
	R22 R23	19A700106P63 3R152P203J	Composition: 1K ohms ±5%, 1/4 w. Composition: 20K ohms ±5%, 1/4 w.									
	R24	19A116559P106	Variable, cermet: 10K ohms ±20%, .5 w; sim to CTS Series 360.									
ANGES							l			L		

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

This addendum describes Revision Letter changes that are not yet included in the publication.

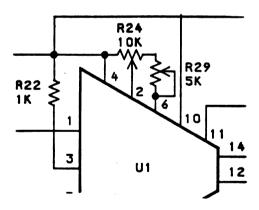
REV.A- 19D423823G1-3 POWER AMPLIFIER BOARD.

TO REDUCE THE PROBABILITY OF P.A. BURN-UP DUE TO MISADJUSTMENT FO EXCESSIVE POWER. ADDED R29. PART NUMBER FOR R29 IS 19A700016P3. VARAIBLE RESISTOR. 5000 OHMS + OR - 10%, 1/2 WATT.

ADJUSTMENT PROCEDURE

- 1. TURN POWER ADJUST CONTROL R24 AND POWER LIMIT CONTROL R29 FULLY CLOCKWISE. NOTE THAT POWER OUTPUT EXCEEDS RATED POWER OUTPUT FOR ALL CHANNELS.
- 2. SET LIMIT CONTROL TO PROVIDE A POWER OUTPUT 1 DB GREATER THAN RATED POWER.

NEW SCHEMATIC IS



NOTE: THE NEW PRINTED WIRE PATTERN IS INCORPORATED IN THIS CHANGE.